Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-363-4672

Inclosure Material:

Glass

Overall Length:

0.098 inches

Overall Height:

0.050 inches

Overall Width:

0.098 inches

Mounting Method:

Terminal

Features Provided:

Electrostatic sensitive

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

22.0 reverse voltage, dc

Current Rating Per Characteristic:

50.00 milliamperes source cutoff current preset and 100.00 nanoamperes forward current, average peak

Power Rating Per Characteristic:

250.0 milliwatts small-signal input power, common-emitter peak

Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius ambient air

Special Features:

Ribbon terminal cut at 45.0 degrees angle is the cathode

Terminal Type And Quantity:

2 ribbon

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0